



REV.	ECN NO OR DESCRIPTION	REVISED	DATE

A

B

C

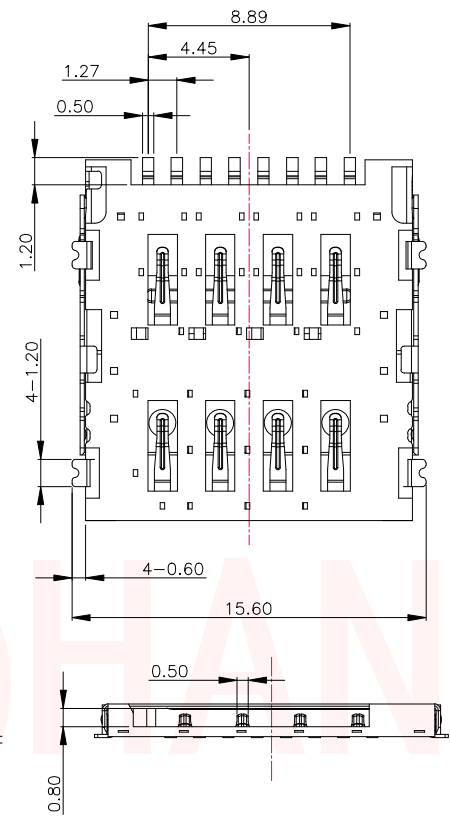
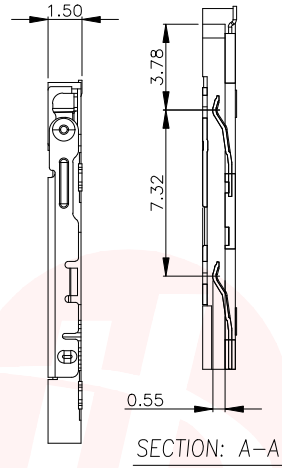
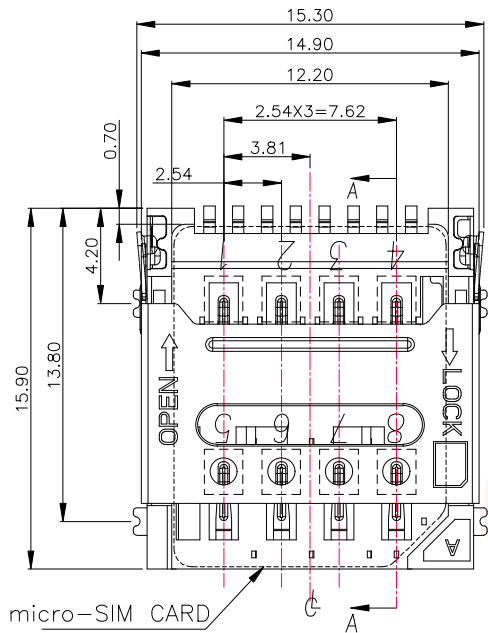
D

A

B

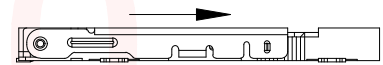
C

D

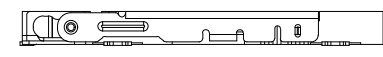


NOTES:

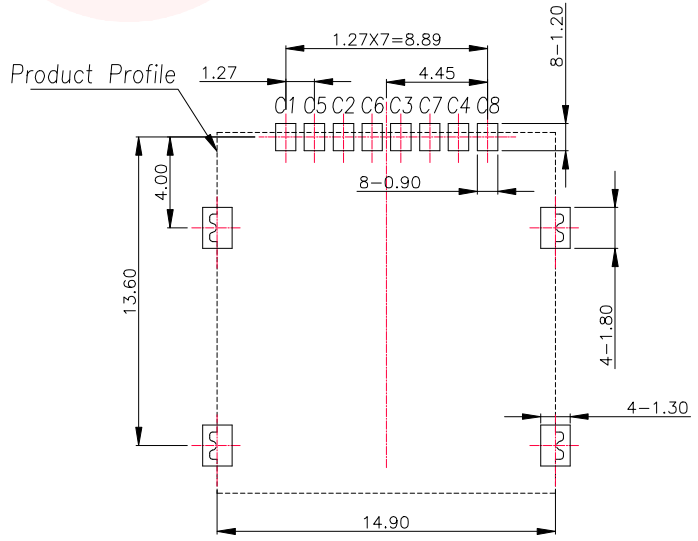
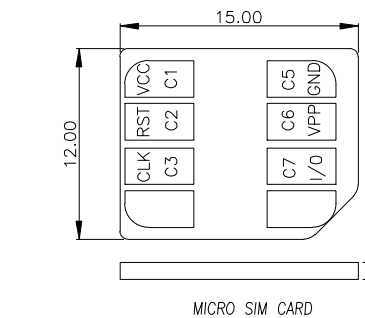
- ELECTRICAL CHARACTERISTICS
  - 1-1. CONTACT RESISTANCE: 60 MILLIOHMS MAX
  - 1-2. INSULATION RESISTANCE: 1,000 MEGOHMS MIN.
  - 1-3. DIELECTRIC WITHSTANDING VOLTAGE: 500V AC FOR 1 MINUTE.
- MECHANICAL CHARACTERISTICS
  - 2-1. OPERATION TEMPERATURE RANGE: -25°C~+70°C
  - 2-2. DURABILITY: 5000 CYCLES
- MATERIAL:
  - 3-1. HOUSING: THERMOPLASTIC,UL 94-V0
  - 3-2. TERMINAL: PHOSPHOR BRONZE,T=0.15
  - 3-3. SHELL: STAINLESS STEEL,T=0.15
- FINISHED:
  - 4-1. TERMINAL: NI PLATED UNDER,AU PLATED ON CONTACT AREA,G/F PLATED ON SOLDER TAIL



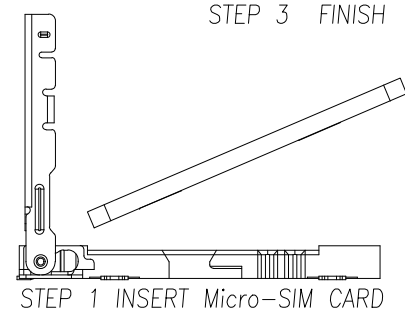
STEP 2 PUSH THE SHELL



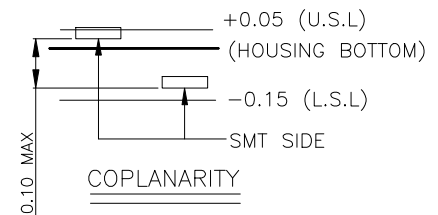
STEP 3 FINISH



RECOMMENDED PCB LAYOUT  
GENERAL TOLERANCE ±0.05



STEP 1 INSERT Micro-SIM CARD



PIN No.	DESCRIPTION
C1	VCC (SUPPLY VOLTAGE)
C2	RST (RESET SIGNAL)
C3	CLK (CLOCK SIGNAL)
C4	RESERVED
C5	GND
C6	VPP (VARIABLE SUPPLY VOLTAGE)
C7	I/O (DATA INPUT/OUTPUT)
C8	RESERVED

UNLESS OTHERWISE SPECIFIED TOLERANCES

DECIMALS:	ANGLES:
X ±0.25	X ±2°
X.X ±0.20	X.X ±1°
X.XX ±0.15	

东莞市汉博电子科技有限公司  
DONGGUAN HANBO TECHNOLOGY CO., LTD

TITLE	MICRO SIM CARD HINGED 8pin H1.5 翻盖式		
DWN	xiong	PART NO.	SNO-1340
CHKD	lee	SCALE:1:1	UNIT: mm
APVD	wang	SIZE: A4	SHEET:1OF 1
			REV: A4
CUSTOMER COPY			